

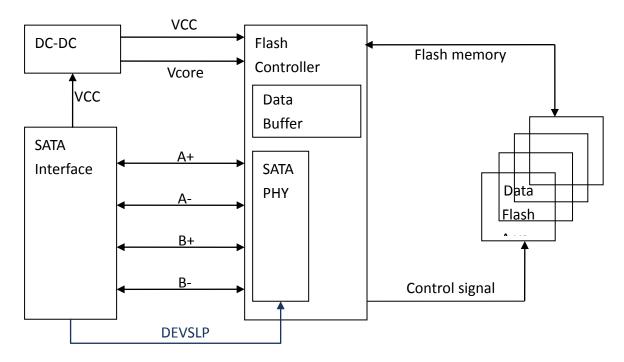
Team Industrial SATAIII M.2 2260 SSD

1. INTRODUCTION

1.1 General Description

Team's M6Q56 M.2 2260 SATA Drive delivers all the advantages of Flash Disk technology with the Serial ATA I/II/III interface and is fully compliant with the standard Next Generation Form Factor (NGFF) called M.2 Card Format, which is generated by Intel. The M.2 2260 SATA Drive is designed to operate at a maximum operating frequency of 200MHz with 30MHz external crystal. Its capacity could provide a wide range up to 512GB. Moreover, it can reach up to 550MB/s read as well as 460MB/s write high performance based on Toshiba NAND flash (with 32MB SDR enabled and measured by CrystalDiskMark v5.0). The power consumption of the M.2 2260 is much lower than traditional Hard Drives, making it the best embedded solution for new platforms.

1.2 Block Diagram





2. PRODUCT SPECIFICATIONS

- Capacity:
 - ➤ MLC: From 32GB up to 512GB(Support 48-bit addressing mode)
- Electrical/Physical Interface:
 - SATA Interface
 - ➤ Compliant with SATA Revision 3.2
 - Compatible with SATA 1.5Gbps, 3Gbps and 6Gbps interface
 - Support power management
 - > Support expanded register for SATA protocol 48 bits addressing mode
 - ➤ Embedded BIST function for SATA PHY for low cost mass production
- Built-in 2-channel NAND flash interface controller
 - Compliant with Toggle 1.0 and Toggle 2.0 NAND Flash interface
 - Compliant with ONFI 4.0 interface:
 - SDR up to mode 5
 - NV-DDR up to mode 5
 - NV-DDR2 up to mode 7
 - NV-DDR3 up to mode 8
- Supported NAND Flash:
 - Support up to 16 Flash Chip Enables (CE) within single design
 - Toshiba 15nm/3D-NAND MLC and TLC
 - Support all types of SLC/MLC/TLC/3D-NAND, 8KB/page and 16K/page NAND flash
 - Support ONFI 2.3, ONFI 3.0, ONFI 3.2 and ONFI 4.0 interface: 2 channels at maximum

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- ECC Scheme
 - Applies the LDPC (Low Density Parity Check) of ECC algorithm
- UART Function
- GPIO
- Support SMART and TRIM commands



Performance

Capacity	Flash	Flash Type	Sequential	
	Structure		Read	Write
32GB	32GB x 1	BGA, 15nm	550	160
64GB	32GB x 2	BGA, 15nm	550	310
128GB	64GB x 2	BGA, 15nm	550	460
256GB	64GB x 4	BGA, 15nm	550	460
512GB	128GB x 4	BGA, 15nm	550	460

Note:

- 1. The performance was estimated based on Toshiba NAND flash.
- 2. Performance may differ according to flash configuration and platform.
- 3. The table above is for reference only.

• TBW (Terabytes Written)

Capacity	Flash Structure	TBW
32GB	32GB x 1	13
64GB	32GB x 2	30
128GB	64GB x 2	87
256GB	64GB x 4	198
512GB	128GB x4	544

Note:

- 1. Samples were built using Toshiba NAND flash.
- 2. TBW may differ according to flash configuration and platform.
- 3. The endurance of SSD could be estimated based on user behavior, NAND endurance cycles, and write amplification factor. It is not guaranteed by flash vendor.



Overview

- Capacity
- ➤ MLC: 32GB up to 512GB
- SATA Interface
- > SATA Revision 3.2
- ➤ SATA 1.5Gbps, 3Gbps, and 6Gbps interface
- Flash Interface
- > Flash Type: MLC
- Performance
- Read: up to 550 MB/s
- Write: up to 460 MB/s
- Power Consumption
- Active mode: < 1740mW
- ► Idle mode: < 265mw
- TBW (Terabyte Written)
- > 544TBW for 512GB

- MTBF
- More than 2,000,000 hours
- Advanced Flash Management
- Static and Dynamic Wear Leveling
- Bad Block Management
- > TRIM
- > SMART
- Over-Provision
- Low Power Management
- > DEVSLP Mode (Optional)
- ➤ DIPM/HIPM Mode
- Temperature Range
- ➤ Operation(Standard): $0 \sim 70 \,^{\circ}\text{C}$ Storage: $-40 \,^{\circ}\text{C} \sim 85 \,^{\circ}\text{C}$
- RoHS compliant



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3. ENVIRONMENTAL SPECIFICATIONS

3.1 Environmental Conditions

3.1.1 Temperature and Humidity

• Storage Temperature Range:

> -40 ℃ ~ 85 ℃

Operation Temperature Range:

> Standard Grade: $0\% \sim 70\%$

• Humidity:

Standard Grade: RH 90% under 40℃ (in operational)

• High Temperature Test Condition:

	Temperature	Humidity	Test Time
Operation (Standard Grade)	70℃	0% RH	72 hours
Storage (Standard Grade)	85℃	0% RH	72 hours

Result: No any abnormality is detected.

• Low Temperature Test Condition:

	Temperature	Humidity	Test Time
Operation (Standard Grade)	\mathfrak{D}	0% RH	72 hours
Storage (Standard Grade)	-40℃	0% RH	72 hours

Result: No any abnormality is detected.

• High Humidity Test Condition:

	Temperature	Humidity	Test Time
Operation (Standard Grade)	40℃	90% RH	4 hours
Storage (Standard Grade)	40℃	93% RH	72 hours

Result: No any abnormality is detected.

• Temperature Cycle Test:

	Temperature	Test Time	Cycle
Operation 0℃		30min	10 Cycle
(Standard Grade)	70℃	30min	
Storage	-40℃	30min	10 Cycle
(Standard Grade)	85℃	30min	

Result: No any abnormality is detected.



3.1.2 Shock:

Shock Specification.

	Acceleration Force	Half Sin Pulse Duration
Non-Operational	1500G	0.5ms

Result: No any abnormality is detected when power on.

3.1.3 Vibration:

Vibration Specification

	Cond	Vibration		
	Frequency/Displacement	Frequency/Acceleration	Orientation	
Non-Operational	20Hz~80Hz/1.52mm	80Hz~2000Hz/20G	X, Y, Z axis/60	
			min for each	

Result: No any abnormality is detected when power on.

3.1.4 Drop:

Drop Specification

	Height of Drop Number of Drop	
Non-Operational	80cm free fall	6 face of each unit, 2 times

Result: No any abnormality is detected when power on.

3.1.5 Bending:

Bending Specification

	Force	Action
Non-Operational	≥ 20N	Hold 1min/5times

Result: No any abnormality is detected when power on.

3.1.6 Electrostatic Discharge (ESD):

• Contact ESD Specification

Device	Condition	Temperature	Relative Humidity	+/- 4KV	Result
				Device functions are	
				affected, but EUT will	
M.2	512GB	24.0℃	49% (RH)	be back to its normal or	PASS
				operational state	
				automatically.	



3.2 MTBF

MTBF, an acronym for Mean Time Between Failures, is a measure of a device's reliability. It value represents the average time between a repair and the next failure. The measure is typically in units of hours. The higher the MTBF value, the higher the reliability of the device. The predicted result of Team M.2 is more than 2,000,000 hours.

3.3 Certification & Compliance

- RoHS
- SATA III (SATA Rev. 3.2)
- Up to ATA/ATAPI-8 (Including S.M.A.R.T)



4. ELECTRICAL SPECIFICATIONS

4.1 Supply Voltage

• Supply Voltage of M.2

Parameter	Rating
Operating Voltage	$3.3V \pm 5\%$

4.2 Power Consumption

• Power Consumption of M.2

Capacity	Flash	Flash Type	Read	Write	Partial	Slumber	Idle	DEVSLP
	Structure							
32GB	32GB x 1	BGA, 15nm	1000	1200	12	7	255	4.9
64GB	32GB x 2	BGA, 15nm	1040	1215	12	7	257	4.9
128GB	64GB x 2	BGA, 15nm	1065	1480	12	7	255	4.9
256GB	64GB x 4	BGA, 15nm	1165	1535	12	7	260	4.9
512GB	128GB x 4	BGA, 15nm	1425	1740	14	10	260	4.9

Unit: mW

Note:

- 1. The average value of power consumption is achieved based on 100% conversion efficiency.
- 2. The measured power voltage is 3.3V.
- 3. Samples were built using Toshiba NAND flash and measured under normal temperature.
- 4. Sequential R/W is measured while testing 4000MB sequential R/W 5 times by CyrstalDiskMark.
- 5. Power Consumption may differ according to flash configuration, SDR configuration, and platform.

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5. INTERFACE

5.1 Pin Assignment and Descriptions

• Pin Assignment and Description of M.2

Pin	Segment	Pin Definition
1	CONFIG_3=GND	Ground
2	3.3V	Supply pin
3	GND	Ground
4	3.3V	Supply pin
5	N/C	No Connect
6	N/C	No Connect
7	N/C	No Connect
8	N/C	No Connect
9	N/C or GND	No Connect or Ground
		(N/C for Socket 2, and GND for Socket 3)
10	DAS/DSS#	Status indicators via LED devices that will be provided by the
	(O)(OD)	system Active Low. A pulled-up LED with series current
		limiting resistor should allow for 9mA when On.
11	N/C	No Connect
12	Module Key	
13	Module Key	
14	Module Key	
15	Module Key	
16	Module Key	
17	Module Key	
18	Module Key	
19	Module Key	
20	N/C	No Connect
21	CONFIG_0=GND	Ground
22	N/C	No Connect
23	N/C	No Connect
24	N/C	No Connect
25	N/C	No Connect
26	N/C	No Connect
27	GND	Ground
28	N/C	No Connect



29	N/C	No Connect
30	N/C	No Connect
31	N/C	No Connect
32	N/C	No Connect
33	GND	Ground
34	N/C	No Connect
35	N/C	No Connect
36	N/C	No Connect
37	N/C	No Connect
		Device Sleep, Input.
38	DEVSLP(I)	When driven high the host is informing the SSD to enter a low power
	(0/3.3V)	state
39	GND	Ground
40	N/C	No Connect
41	SATA-B+	SATA differential signals in the SATA specification
42	N/C	No Connect
43	SATA-B-	SATA differential signals in the SATA specification
44	N/C	No Connect
45	GND	Ground
46	N/C	No Connect
47	SATA-A-	SATA differential signals in the SATA specification
48	N/C	No Connect
49	SATA-A+	SATA differential signals in the SATA specification
50	N/C	No Connect
51	GND	Ground
52	N/C	No Connect
53	N/C	No Connect
54	N/C	No Connect
55	N/C	No Connect
		Manufacturing Data line. Used for SSD manufacturing only.
56	Reserved for MFG	
	Data	Not used in normal operation. Pins should be left N/C in
		platform Socket
57	GND	Ground
		Manufacturing Clock line. Used for SSD manufacturing only.
58	Reserved for MFG	
	Clock	Not used in normal operation. Pins should be left N/C in

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		platform Socket
59	Module Key	
60	Module Key	
61	Module Key	
62	Module Key	
63	Module Key	
64	Module Key	
65	Module Key	
66	Module Key	
67	N/C	No Connect
68	SUSCLK(I)(0/3.3V)	32 KHz clock supply input that is provided by PCH to reduce
		power and cost for the module.
69	CONFIG_1=GND	Defines module type
70	3.3V	Supply pin
71	GND	Ground
72	3.3V	Supply pin
73	GND	Ground
74	3.3V	Supply pin
75	CONFIG_2=GND	Ground

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6. SUPPORTED COMMANDS

6.1 ATA Command List

Op-Code	Command Description	Op-C	Code	Command Description
00h	NOP	60h		Read FPDMA Queued
06h	Data Set Management	61h		Write FPDMA Queued
10h	Recalibrate	70h		Seek
20h	Read Sectors	90h		Execute Device Diagnostic
21h	Read Sectors without Retry	91h		Initialize Device Parameters
24h	Read Sectors EXT	92h		Download Microcode
25h	Read DMA EXT	93h		Download Microcode DMA
27h	Read Native Max Address EXT	B0h		SMART
29h	Read Multiple EXT	B0h	D0h	SMART READ DATA
2Fh	Read Log EXT	B0h	D1h	SMART READ DATA ATTRIBUTE THRESHOLD
30h	Write Sectors	B0h	D2h	SMART ENABLE/DISABLE ATTRIBUTE AUTOSAVE
31h	Write Sectors without Retry	B0h	D3h	SMART SAVE ATTRIBUTE VALUES
34h	Write Sectors EXT	B0h	D4h	SMART EXECUTE OFF-LINE IMMEDIATE
35h	Write DMA EXT	B0h	D5h	SMART READ LOG
37h	Set Native Max Address EXT	B0h	D6h	SMART WRITE LOG
39h	Write Multiple EXT	B0h	D8h	SMART ENABLE OPERATIONS
3Dh	Write DMA FUA EXT	B0h	D9h	SMART DISABLE OPERATIONS
3Fh	Write Long EXT	B0h	DAh	SMART RETURN STATUS
40h	Read Verify Sectors	B0h	DBh	SMART ENABLE/DISABLE AUTOMATIC OFF-LINE
41h	Read Verify Sectors without Retry	B1h	<u>'</u>	DEVICE CONFIGURATION OVERLAY
42h	Read Verify Sectors EXT	B1h	C0h	DEVICE CONFIGURATION RESTORE
45h	Write Uncorrectable EXT	B1h	C1h	DEVICE CONFIGURATION FREEZE LOCK
47h	Read Log DMA EXT	B1h	C2h	DEVICE CONFIGURATION



						IDENTIFY
57h		Write Log DMA EXT	B1h	C	3h	DEVICE CONFIGURATION
						SET
B1h	C4h	DEVICE CONFIGURATION	ECh			Identify Device
		IDENTIFY DMA				
B1h	C5h	DEVICE CONFIGURATION	EFh			Set Features
		SET DMA				
C4h		Read Multiple	EFh	0	2h	Enable 8-bit PIO transfer mode
C5h		Write Multiple	EFh	03h		Set transfer mode based on value
						in Count field
C6h		Set Multiple Mode	EFh	05h		Enable advanced power
		•				management
C8h		Read DMA	EFh	10h	1	Enable use of Serial ATA feature
C9h		Read DMA without Retry	EFh	10h	02h	Enable DMA Setup FIS
		·				Auto-Activate optimization
CAh		Write DMA	EFh	10h	03h	Enable Device-initiated interface
						power state (DIPM) transitions
CBh		Write DMA without Retry	EFh	10h	06h	Enable Software Settings
						Preservation (SSP)
CEh		Write Multiple FUA EXT	EFh	10h	07h	Enable Device Automatic Partial
701		a " * "		4.01	0.01	to Slumber transitions
E0h		Standby Immediate	EFh	10h	09h	Enable Device Sleep
E1h		Idle Immediate	EFh	55h		Disable read look-ahead feature
E2h		Standby	EFh	66h		Disable reverting to power-on
F01		Y 11		0.21		defaults
E3h		Idle	EFh	82h		Disable write cache
E4h		Read Buffer	EFh	85h		Disable advanced power
E.61		Cl. 1 D. M. 1	DDI.	0.01		management
E5h		Check Power Mode	EFh	h 90h		Disable use of Serial ATA feature
						Set Disable DMA Setup EIS
E6h	Sleep EFh 90h (02h	Disable DMA Setup FIS		
						Auto-Activate optimization Disable Device-initiated interface
E7h		Flush Cache	EFh	90h	03h	power state (DIPM) transitions
						Disable Software Settings
E8h		Write Buffer	EFh	90h	06h	Preservation (SSP)
E9h		Read Buffer DMA	EFh	006	07h	Disable Device Automatic Partial
Liffi		Read Duller DIVIA	171,11	Fh 90h 07h		Disable Device Automatic Faltian



						to Slumber transitions
EAh		Flush Cache EXT	EFh 90h 09h		09h	Disable Device Sleep
EBh		Write Buffer DMA	EFh AAh			Enable read look-ahead feature
EFh	CCh	Enable reverting to power-on	F4h			Security Erase Unit
		defaults				
F1h		Security Set Password	F5h			Security Freeze Lock
F2h		Security Unlock	F6h			Security Disable Password
F3h		Security Erase Prepare	F8h			Read Native Max Address

6.2 Identify Device Data

The following table details the sector data returned by the IDENTIFY DEVICE command.

Word	F:Fixed V:Variable	Default Value	Description
	X:Both		
0	F	0040h	General configuration bit-significant
			information
1	X	*1	Obsolete – Number of logical cylinders
2	V	C837	Specific configuration
3	X	0010h	Obsolete – Number of logical heads
			(16)
4-5	X	00000000h	Retired
6	X	003Fh	Obsolete – Number of logical sectors
			per logical track (63)
7-8	V	00000000h	Reserved for assignment by the
			Compact Flash Association
9	X	0000h	Retired
10-19	F	Varies	Serial number (20 ASCII characters)
20-21	X	0000h	Retired
22	X	0000h	Obsolete
23-26	F	Varies	Firmware revision (8 ASCII characters)
27-46	F	Varies	Model number (xxxxxxxx)
47	F	8010h	7:0- Maximum number of sectors
			transferred per interrupt on MULTIPLE
			commands
48	F	4000h	Trusted Computing feature set
			options(not support)



49	F	2F00h	Capabilities
50	F	4000h	Capabilities
51-52	X	00000000h	Obsolete
53	F	0007h	Words 88 and 70:64 valid
54	X	*1	Obsolete – Number of logical cylinders
55	X	0010h	Obsolete – Number of logical heads
			(16)
56	X	003Fh	Obsolete – Number of logical sectors
			per track (63)
57-58	X	*2	Obsolete – Current capacity in sectors
59	F	0110h	Number of sectors transferred per
			interrupt on MULTIPLE commands
60-61	F	*3	Maximum number of sector (28bit
			LBA mode)
62	X	0000h	Obsolete
63	F	0407h	Multi-word DMA modes
			supported/selected
64	F	0003h	PIO modes supported
65	F	0078h	Minimum Multiword DMA transfer
			cycle time per word
66	F	0078h	Manufacturer's recommended
			Multiword DMA transfer cycle time
67	F	0078h	Minimum PIO transfer cycle time
			without flow
68	F	0078h	Minimum PIO transfer cycle time with
			IORDY flow control
69	F	0100h	Additional Supported (support
			download microcode
70	F	0000h	Reserved
71-74	F	000000000000000000h	Reserved for the IDENTIFY PACKET
			DEVICE command
75	F	001Fh	Queue depth
76	F	670eh	Serial SATA capabilities
77	F	0084h	Serial ATA Additional Capabilities
78	F	014Ch	Serial ATA features supported
79	V	0040h	Serial ATA features enabled
80	F	07F8h	Major Version Number



81	F	0000h	Minor Version Number
82	F	346bh	Command set supported
83	F	7d09h	Command set supported
84	F	6063h	Command set/feature supported
			extension
85	V	3469h	Command set/feature enabled
86	V	bc01h	Command set/feature enabled
87	V	6063h	Command set/feature default
88	V	003Fh	Ultra DMA Modes
89	F	0001h	Time required for security erase unit
			completion
90	F	001Eh	Time required for Enhanced security
			erase
91	V	0000h	Current advanced power management
			value
92	V	FFFEh	Master Password Revision Code
93	F	0000h	Hardware reset result. The contents of
			the bits (12:0) of this word can be
			changed only during the execution of
			hardware reset.
94	V	0000h	Vendor's recommended and actual
			acoustic management value
95	F	0000h	Stream Minimum Request Size
96	V	0000h	Streaming Transfer Time – DMA
97	V	0000h	Streaming Access Latency – DMA and
			PIO
98-99	F	0000h	Streaming Performance Granularity
100-103	V	*4	Maximum user LBA for 48 bit Address
104	T 7	00001	feature set
104	V	0000h	Streaming Transfer Time – PIO
105	F	0008h	Maximum number of 512-byte blocks
			per DATA SET MANAGEMENT
106	F	4000h	command Physical sector size/Logical sector size
100	<u>г</u> 	0000h	
107	Г	UUUUII	Inter-seek delay for ISO-7779 acoustic testing in microseconds
108-111	F	000000000000000	Unique ID
100-111	1.	00000000000000000h	Omque ID



112-115	F	000000000000000000000h	Reserved
116	V	0000h	Reserved
117-118	F	00000000h	Words per logical Sector
119	F	4014h	Supported settings
120	F	4014h	Command set/Feature
			Enabled/Supported
121-126	F	0h	Reserved
127	F	0h	Removable Media Status Notification
			feature set support
128	V	0021h	Security status
129-140	X	0h	Vendor specific
141	X	0001h	Vendor specific
142-159	X	0h	Vendor specific
160	F	0h	Compact Flash Association (CFA)
			power mode 1
161-167	X	0h	Reserved for assignment by the CFA
168	F	3h 2.5 inch	Device Nominal Form Factor
		4h 1.8 inch	
		5h Less than 1.8inch	
169	F	0001h	DATA SET MANAGEMENT
			command is
170-173	F	Oh	Additional Product Identifier
174-175		Oh	Reserve
176-205	V	Oh	Current media serial number
206	F	Oh	SCT Command Transport
207-208	F	Oh	Reserved
209	F	4000h	Alignment of logical blocks within a
			physical block
210-211	V	0000h	Write-Read-Verify Sector Count Mode
			3 (not support)
212-213	F	0000h	Write-Read-Verify Sector Count Mode
21121		00001	2 (not support)
214-216	T-	0000h	NV Cache relate (not support)
217	F	0001h	Non-rotating media device
218	F	Oh	Reserved
219	F	Oh	NV Cache relate (not support)
220	V	Oh	Write read verify feature set current



			mode	
221		0h	Reserved	
222	F	107Fh	Transport major version number	
223	F	0h	Transport minor version number	
224-229		0h	reserved	
230-233		0h	Extend number of user addressable	
			sectors	
234		0001h	Minimum number of 512-byte data	
			blocks per DOWNLOAD	
			MICROCODE command for mode	
235		0080h	Maximum number of 512-byte data	
			blocks per DOWNLOAD	
			MICROCODE command for mode	
236-254	F	0h	Reserved	
255	X	XXA5h XX is variable	Integrity word (Checksum and	
			Signature)	

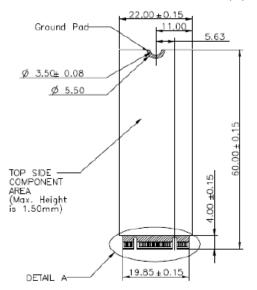
• List of Device Identification for Each Capacity

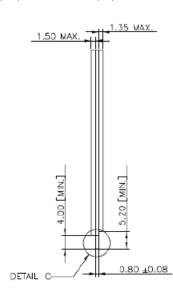
Capacity	*1	*2	*3	*4
(GB)	(Word 1/Word 54)	(Word 57 - 58)	(Word 60 - 61)	(Word 100 - 103)
32	3FFFh	FBFC10h	3BA2EB0h	3BA2EB0h
64	3FFFh	FBFC10h	7740AB0h	7740AB0h
128	3FFFh	FBFC10h	EE7C2B0H	EE7C2B0H
256	3FFFh	FBFC10h	FFFFFFFh	1DCF32B0h
512	3FFFh	FBFC10h	FFFFFFFh	3B9E12B0h

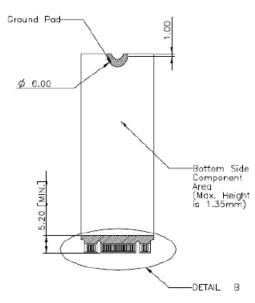


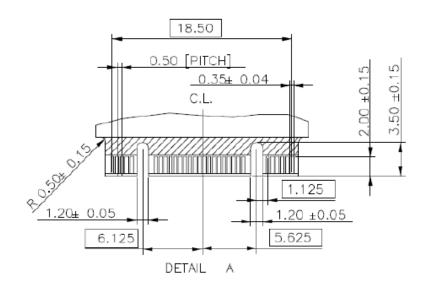
7. PHYSICAL DIMENSION

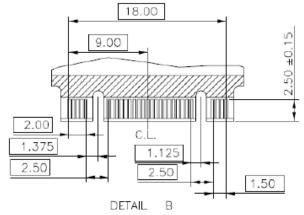
• Dimension: 60mm(L) x 22mm(W) x 3.75mm(H)

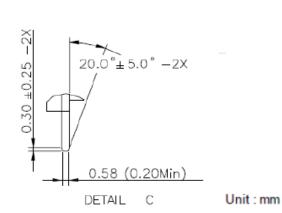








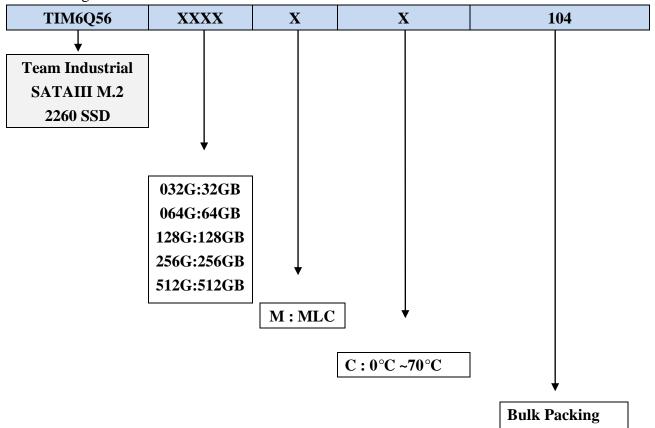






8. PRODUCT ORDERING NUMBER

The ordering number rule is as below:



The products list is as below:

Capacity	Product Ordering Number	
32GB	TIM6Q56032GMC104	
64GB	TIM6Q56064GMC104	
128GB	TIM6Q56128GMC104	
256GB	TIM6Q56256GMC104	
512GB	TIM6Q56512GMC104	



9. REVISION HISTORIES

Version	Revision Description	Date	Issued By	Authorized By
A01	Initial Release	2017/12/14	Jerry.Chien	Tommy.Hua